

ICND2019

(8-Channel Power Switch for LED Display)



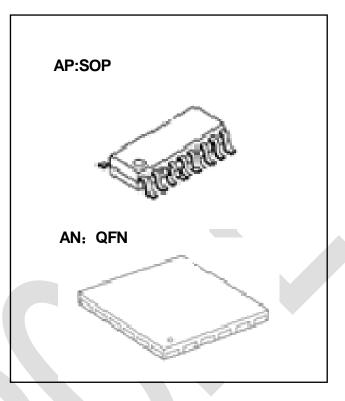
Description

ICND2019 is a 8-channel power switch for LED display.ICND2019 Integrated 74HC595 (8-bit serial-in, serial parallel-out shift register) and 8 Channel N-Channel Enhancement Mode MOSFET driver.

ICND2019 integrated Ghosting Reduction, Caterpillar Cancelling and LED Protection circuit.

Features

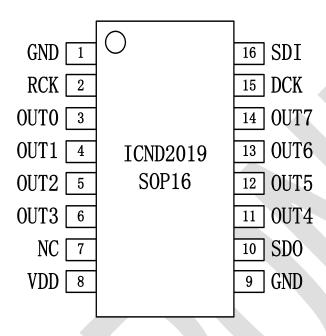
- Integrated 74HC595 (8-bit serial-in, serial parallel-out shift register)
- ♦ 8 Channel N-Channel Enhancement Mode MOSFET driver
- ♦ N-MOSTEF Rds(ON) 100 mΩ, Max output current 2.5A
- ♦ Ghosting Reduction
- ♦ Caterpillar Removal for LED Short
- ♦ LED Protection
- ♦ Max Power Dissipation <625mW @ VDD=5V & Ivdd=2.5A</p>
- ♦ Up Ghosting Level Adjustable





Pin Configuration

1 AP: SOP16



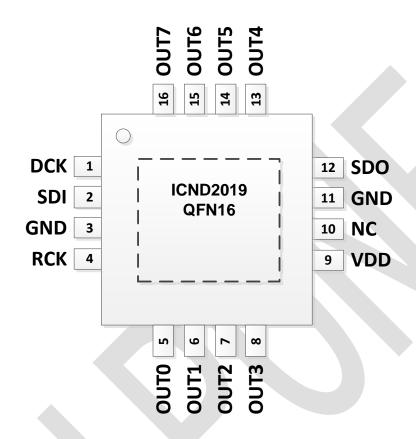
ICND2019AP (SOP16)					
Pin No	Pin Name	Function			
1, 9	GND	Power Ground			
2	RCK	Register Input			
3~6,11~14	OUT0~OUT7	Output with N-Channel Enhancement Mode MOSFET			
7	NC	Not Connected			
8	VDD	Power-Supply Voltage			
10	SDO	Serial Data Output			
15	DCK	Shift Clock Input			
16	SDI	Serial Data Input			

Note:

For control card, SDI is the C of 3-8 decoder, DCK is the A of 3-8 decoder, RCK is the B of 3-8 decoder



2 AN: QFN16



ICND2019AN (QFN16)				
Pin No	Pin Name	Function		
1	DCK	Shift Clock Input		
2	SDI	Serial Data Input		
3,11	GND	Power Ground		
4	RCK	Register Input		
5~8,	OUT0~OUT3,	Output with N-Channel Enhancement Mode		
13~16	OUT4~OUT7	MOSFET		
9	VDD	Power-Supply Voltage		
10	NC			
12	SDO	Serial Data Output		

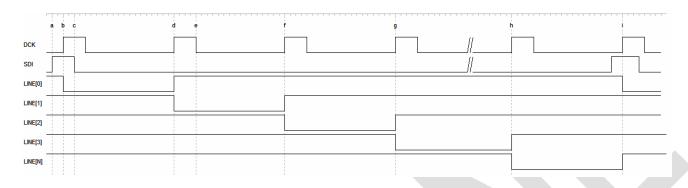
Note:

For control card, SDI is the C of 3-8 decoder, DCK is the A of 3-8 decoder, RCK is the B of 3-8 decoder



Time Waveform

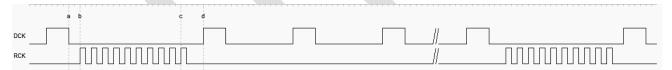
The rising edge of DLK is a line feed signal. After receiving the rising edge of DCLK, the data is shifted once, and the corresponding open channel is also shifted. The width of DCLK is the elimination time, so we need to do DCLK width and interface elimination parameter linkage.



Time	Function	MIN
Tb-Td	Display time, between the two DCLK rising edge	
Te-Tf	Registers configure time ,the DLCK falling edge to the next rising edge	
Td-Te	Ghost reduction time, DCLK pulse width	500ns
Ta-Tb	Setup time	20ns
Tb-Tc	Hold time	20ns

Register Setting

Ta-Td, Registers configure time, the DLCK falling edge to the next rising edge.



Register and Number of RCLK Rising Edge when DCK is High.

Reg[3:0]=RCLK-8

Time	Function	MIN
Tb-Tc	Register configuration time (Reg[3:0]=RCLK-8)	
Ta-Tb	Register configuration pre blank area	100ns
Tc-Td	Register configuration behind blank area	100ns



Register

Number of RCK Rising Edge when DCLK is Low	Model<3:2>	Mode I	Level <1:0>	Level (V)
8			00	2. 5
9	00	1	01	2. 75
10	00	l	10	3. 0
11			11	3. 25
12	01	2	00	2. 5
13			01	2. 75
14			10	3. 0
15			11	3. 25
16		3	00	2. 5
17	10		01	2. 75
18	10		10	3. 0
19			11	3. 25
20	11		00	2. 5
21		0	01	2. 75
22		U	10	3. 0
23			11	3. 25

Default<3:0>=1111





Specifications

Maximum Ratings (Ta =25℃)

Characteristics	Symbol	Rating	Unit
Supply Voltage	VDD	-0.5 ~ + 6.0	V
Input Voltage	VIN	-0.5 ∼ VDD+0.5	V
Power Dissipation	PD	<625	mW
Operating Temperature	Topt	-40 ∼ +80	°C
Storage Temperature	Tstg	-50 ∼ + 150	°C

DC Items (Unless otherwise specified, T_a =-40 $^{\circ}$ C~85 $^{\circ}$ C)

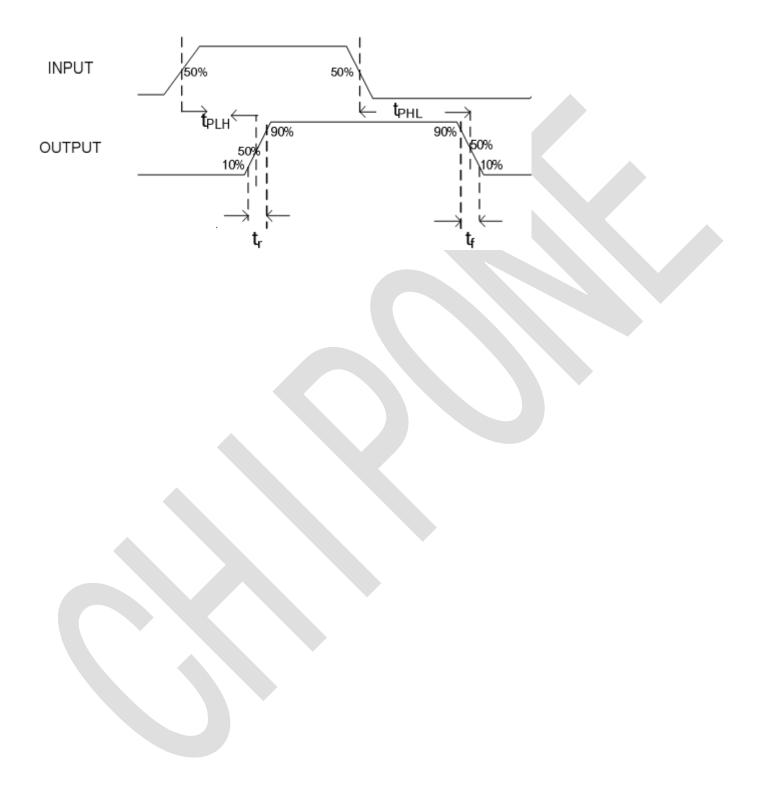
Characteristics	Symbol	Min	Тур	Max	Unit	Test Conditions
Power Supply Voltage	VDD	3.0	5.0	5.5	V	-
High Level Logic Input Voltage	VIH	3.0			V	VDD=5.0V
High Level Logic Input Voltage	VIL			2.0	V	VDD=5.0V
Quiescent Device Current	IDD		2.8		mA	VDD=5.0V
Drain Current	Юн		7	2.5	А	VDD=5.0V
Drain-Source On-State Resistance	RDS(on)		100		mΩ	VDD=5.0V

Switching Characteristics (Unless otherwise specified, T_a =25°C, V_{DD} =5.0V)

Characteristics	Symbol	Min	Тур	Max	Unit	Test conditions
Propagation	t PLH		95		nS	VDD=5.0V
Delay Time	t PHL		36		nS	CL=2nF
Output rise Time	tr		90		nS	
Output fall Time	tf		62		nS	



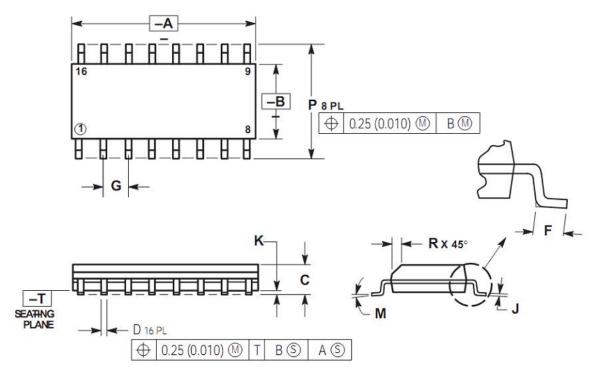
Waveform





Package Outline

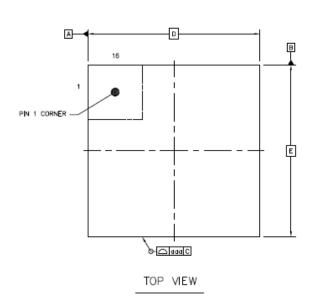
S0P16

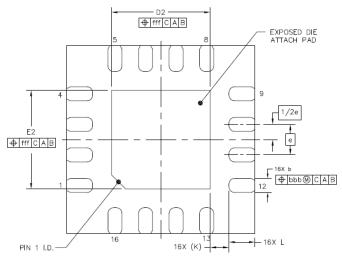


DIM	MILLI	METERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.2	7 BSC	0.050	BSC
J	0.19	0.25	0.008	0.009
К	0.10	0.25	0.004	0.009
М	0°	7°	0°	7°
Р	5.80	6.20	0.229	0.224
R	0.25	0.50	0.010	0.019

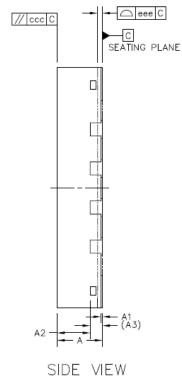


QFN16





BOTTOM VIEW



		SYMBOL	MIN	NOM	MAX
TOTAL THICKNESS		А	0.7	0.75	0.8
STAND OFF		A1	0	0.02	0.05
MOLD THICKNESS		A2		0.55	
L/F THICKNESS		А3		0.203 REF	
LEAD WIDTH		b	0.25	0.3	0.35
BODY SIZE	X	D		4 BSC	
BODT SIZE	Y	E	4 BSC		
LEAD PITCH		е	0.65 BSC		
EP SIZE	X	D2	2	2.1	2.2
EP SIZE	Y	E2	2	2.1	2.2
LEAD LENGTH		L	0.45	0.55	0.65
LEAD TIP TO EXPOSED	PAD EDGE	K	0.4 REF		
PACKAGE EDGE TOLERA	NCE	aaa	0.1		
MOLD FLATNESS		ccc	0.1		
COPLANARITY		eee	0.08		
LEAD OFFSET		bbb	0.1		
EXPOSED PAD OFFSET		fff	0.1		



Product Ordering Information

Product number	Package (Pb-Free)	Package (mm)	Weight (mg)
ICND2019AP	S0P16	9. 9*3. 9*1. 4	159. 5
I CND2019AN	QFN16	4*4*0. 75	

Revision History

Rev	Date	Description
1.0	2018/09	Initial Release
1. 1	2019/04	Add Register
1.2	2019/05	Add QFN Package



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